MJ2955 (See 2N3055) MJ2955A (See 2N3055A)

# Medium-Power Complementary Silicon Transistors

 $\ldots$  for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain hFE = 4000 (Typ) @ IC = 5.0 Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

#### **MAXIMUM RATINGS**

| Rating   | Symbol                            | MJ2500<br>MJ3000 | MJ2501<br>MJ3001 | Unit          |
|--|-----------------------------------|------------------|------------------|---------------|
| Collector–Emitter Voltage  | VCEO                              | 60               | 80               | Vdc           |
| Collector–Base Voltage   | V <sub>CB</sub>                   | 60               | 80               | Vdc           |
| Emitter-Base Voltage   | VEB                               | 5.0              |                  | Vdc           |
| Collector Current  | IC                                | 10               |                  | Adc           |
| Base Current   | lΒ                                | 0.2              |                  | Adc           |
| Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C | PD                                | 150<br>0.857     |                  | Watts<br>W/°C |
| Operating and Storage Junction<br>Temperature Range                | T <sub>J</sub> , T <sub>stg</sub> | -55 to +200      |                  | °C            |

#### THERMAL CHARACTERISTICS

| Characteristic                       | Symbol | Max  | Unit |
|--------------------------------------|--------|------|------|
| Thermal Resistance, Junction to Case | θJC    | 1.17 | °C/W |

## PNP **MJ2500**

MJ2501\* MJ3000

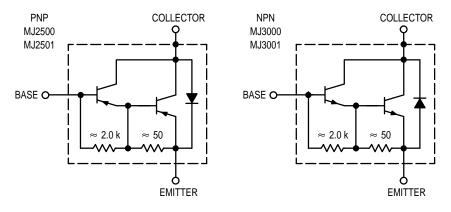
MJ3001<sup>\*</sup>

\*Motorola Preferred Device

10 AMPERE
DARLINGTON
POWER TRANSISTORS
COMPLEMENTARY
SILICON
60-80 VOLTS
150 WATTS



CASE 1-07 TO-204AA (TO-3)



**Figure 1. Darlington Circuit Schematic** 

Preferred devices are Motorola recommended choices for future use and best overall value.

#### REV 7



**ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

| Characteristic  |  | Symbol           | Min              | Max                      | Unit |
|---|--|------------------|------------------|--------------------------|------|
| OFF CHARACTERISTICS   |  |                  |                  |                          |      |
| Collector Emitter Breakdown Voltage <sup>(1)</sup> (IC = 100 mAdc, IB = 0)  | MJ2500, MJ3000<br>MJ2501, MJ3001                                     | V(BR)CEO         | 60<br>80         | —<br>—                   | Vdc  |
| Collector–Emitter Leakage Current (VEB = $60$ Vdc, RBE = $1.0$ k ohm) (VEB = $80$ Vdc, RBE = $1.0$ k ohm) (VEB = $60$ Vdc, RBE = $1.0$ k ohm, TC = $150^{\circ}$ C) (VEB = $80$ Vdc, RBE = $1.0$ k ohm, TC = $150^{\circ}$ C) | MJ2500, MJ3000<br>MJ2501, MJ3001<br>MJ2500, MJ3000<br>MJ2501, MJ3001 | ICER             | _<br>_<br>_<br>_ | 1.0<br>1.0<br>5.0<br>5.0 | mAdc |
| Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc, I <sub>C</sub> = 0)  |  | I <sub>EBO</sub> | _                | 2.0                      | mAdc |
| Collector Emitter Leakage Current ( $V_{CE} = 30 \text{ Vdc}$ , $I_{B} = 0$ ) ( $V_{CE} = 40 \text{ Vdc}$ , $I_{B} = 0$ )   | MJ2500, MJ3000<br>MJ2501, MJ3001                                     | ICEO             | _<br>_           | 1.0<br>1.0               | mAdc |
| ON CHARACTERISTICS <sup>(1)</sup>   |  |                  |                  |                          |      |
| DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 3.0 Vdc)   |  | hFE              | 1000             | _                        | _    |
| Collector–Emitter Saturation Voltage ( $I_C = 5.0$ Adc, $I_B = 20$ mAdc) ( $I_C = 10$ Adc, $I_B = 50$ mAdc)   |  | VCE(sat)         |                  | 2.0<br>4.0               | Vdc  |

Base Emitter Voltage (I<sub>C</sub> = 5.0 Adc, V<sub>CE</sub> = 3.0 Vdc) (1) Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

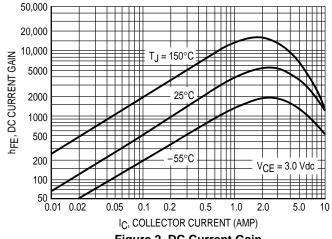


Figure 2. DC Current Gain

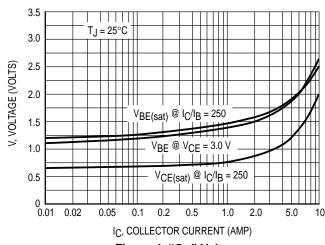
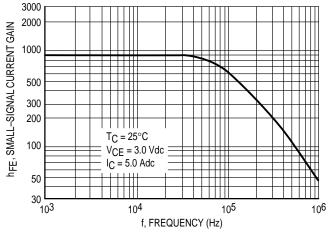


Figure 4. "On" Voltages

There are two limitations on the power handling ability of a transistor: junction temperature and secondary breakdown. Safe operating area curves indicate IC - VCE limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation



VBE(on)

3.0

Vdc

Figure 3. Small-Signal Current Gain

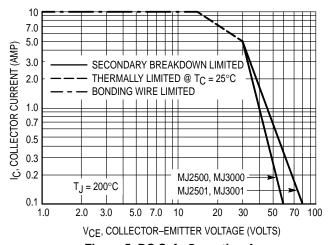
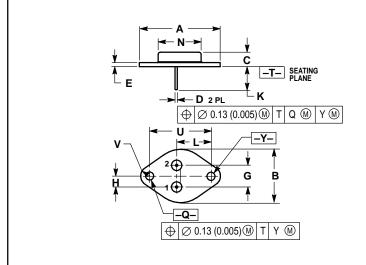


Figure 5. DC Safe Operating Area

than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

### **PACKAGE DIMENSIONS**



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

|     | INCHES    |       | MILLIMETERS |       |  |
|-----|-----------|-------|-------------|-------|--|
| DIM | MIN       | MAX   | MIN         | MAX   |  |
| Α   | 1.550 REF |       | 39.37 REF   |       |  |
| В   |           | 1.050 |             | 26.67 |  |
| С   | 0.250     | 0.335 | 6.35        | 8.51  |  |
| D   | 0.038     | 0.043 | 0.97        | 1.09  |  |
| Е   | 0.055     | 0.070 | 1.40        | 1.77  |  |
| G   | 0.430 BSC |       | 10.92 BSC   |       |  |
| Н   | 0.215     | BSC   | 5.46 BSC    |       |  |
| K   | 0.440     | 0.480 | 11.18       | 12.19 |  |
| L   | 0.665 BSC |       | 16.89 BSC   |       |  |
| N   |           | 0.830 |             | 21.08 |  |
| ø   | 0.151     | 0.165 | 3.84        | 4.19  |  |
| 5   | 1.187     | BSC   | 30.15 BSC   |       |  |
| ٧   | 0.131     | 0.188 | 3.33        | 4.77  |  |

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

**CASE 1-07** TO-204AA (TO-3) ISSUE Z

#### MJ2500 MJ2501 MJ3000 MJ3001

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